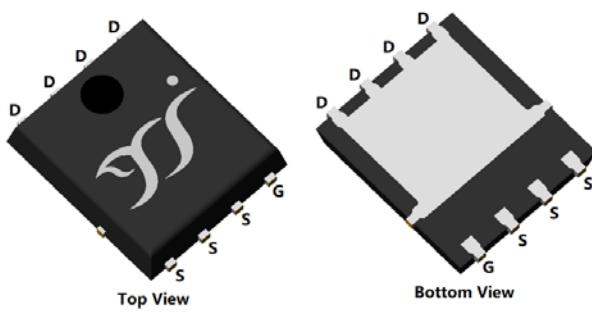
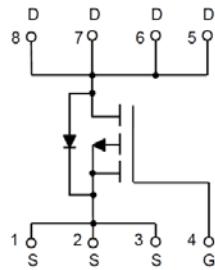


## P-Channel Enhancement Mode Field Effect Transistor



**PDFN5060-8L**



### Product Summary

- $V_{DS}$  -60 V
- $I_D$  -80 A
- $R_{DS(ON)}$  (at  $V_{GS}=-10V$ ) <8.5mΩ
- 100% EAS Tested
- 100%  $\nabla V_{DS}$  Tested

### General Description

- Split gate trench MOSFET technology
- Low  $R_{DS(on)}$  & FOM
- Excellent stability and uniformity
- Moisture Sensitivity Level 3
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free
- Part no. with suffix "Q" means AEC-Q101 qualified

### Applications

- Power management
- Portable equipment
- 12 and 24V Automotive systems

### ■ Absolute Maximum Ratings ( $T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source Voltage	$V_{DS}$	-60	V
Gate-source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current	$I_D$	-12	A
		-7.5	
		-80	
		-50	
Pulsed Drain Current <sup>A</sup>	$I_{DM}$	-320	A
Avalanche energy <sup>B</sup>	EAS	400	mJ
Total Power Dissipation <sup>C</sup>	$P_D$	2.5	W
		1	
		120	
		48	
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~+150	°C

### ■ Thermal resistance

Parameter	Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient <sup>D</sup>	$R_{\theta JA}$	40	50	°C/W
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	0.8	1.04	



# YJG80GP06BQ

## ■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJG80GP06BQ	F1	YJG80GP06B	5000	10000	100000	13" reel

## ■ Electrical Characteristics ( $T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
<b>Static Parameter</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-60	-	-	V
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=-60\text{V}, V_{\text{GS}}=0\text{V}$	-	-	-1	$\mu\text{A}$
Gate-Body Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm100$	nA
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-2	-2.7	-4	V
Static Drain-Source On-Resistance	$R_{\text{DS(on)}}$	$V_{\text{GS}}=-10\text{V}, I_{\text{D}}=-20\text{A}$	-	6.1	8.5	$\text{m}\Omega$
Diode Forward Voltage	$V_{\text{SD}}$	$I_{\text{S}}=-20\text{A}, V_{\text{GS}}=0\text{V}$	-	-0.9	-1.3	V
Gate resistance	$R_{\text{G}}$	f=1MHz, Open drain	-	10	-	$\Omega$
Maximum Body-Diode Continuous Current	$I_{\text{S}}$		-	-	-80	A
<b>Dynamic Parameters</b>						
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=-25\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	5500	-	pF
Output Capacitance	$C_{\text{oss}}$		-	1555	-	
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	220	-	
<b>Switching Parameters</b>						
Total Gate Charge	$Q_{\text{g}}$	$V_{\text{GS}}=-10\text{V}, V_{\text{DS}}=-30\text{V}, I_{\text{D}}=-20\text{A}$	-	80.7	-	nC
Gate-Source Charge	$Q_{\text{gs}}$		-	19	-	
Gate-Drain Charge	$Q_{\text{gd}}$		-	18.3	-	
Reverse Recovery Charge	$Q_{\text{rr}}$	$I_{\text{F}}=-20\text{A}, \text{di}/\text{dt}=100\text{A}/\text{us}$	-	84	-	nC
Reverse Recovery Time	$t_{\text{rr}}$		-	57.5	-	ns
Turn-on Delay Time	$t_{\text{D(on)}}$	$V_{\text{GS}}=-10\text{V}, V_{\text{DD}}=-40\text{V}, R_{\text{GEN}}=1.6\Omega, I_{\text{D}}=-20\text{A}$	-	13.2	-	ns
Turn-on Rise Time	$t_{\text{r}}$		-	27.7	-	
Turn-off Delay Time	$t_{\text{D(off)}}$		-	137.8	-	
Turn-off fall Time	$t_{\text{f}}$		-	59.5	-	

A. Repetitive rating; pulse width limited by max. junction temperature.

B.  $T_J=25^\circ\text{C}, V_{\text{DD}}=-40\text{V}, V_{\text{GS}}=-10\text{V}, L=2\text{mH}, I_{\text{AS}}=-20\text{A}$ .

C.  $P_d$  is based on max. junction temperature, using junction-case and junction-ambient thermal resistance.

D. The value of  $R_{\text{d}}/\text{JA}$  is measured with the device mounted on the 40mm\*40mm\*1.1mm FR-4 PCB board with 1 in2 pad of 2oz. Copper, in the still air environment with  $TA = 25^\circ\text{C}$ . The maximum allowed junction temperature of  $150^\circ\text{C}$ . The value in any given application depends on the user's specific board design.



## ■ Typical Electrical and Thermal Characteristics Diagrams

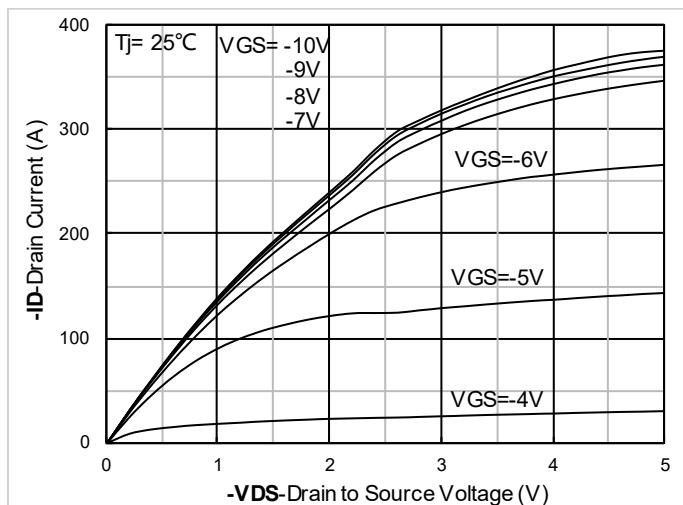


Figure 1. Output Characteristics

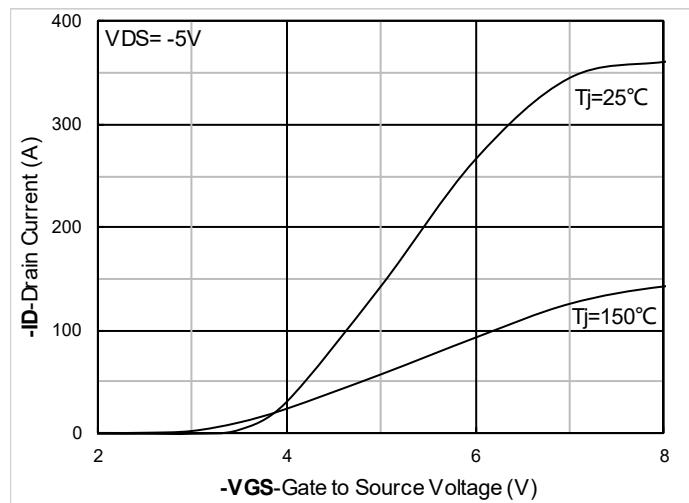


Figure 2. Transfer Characteristics

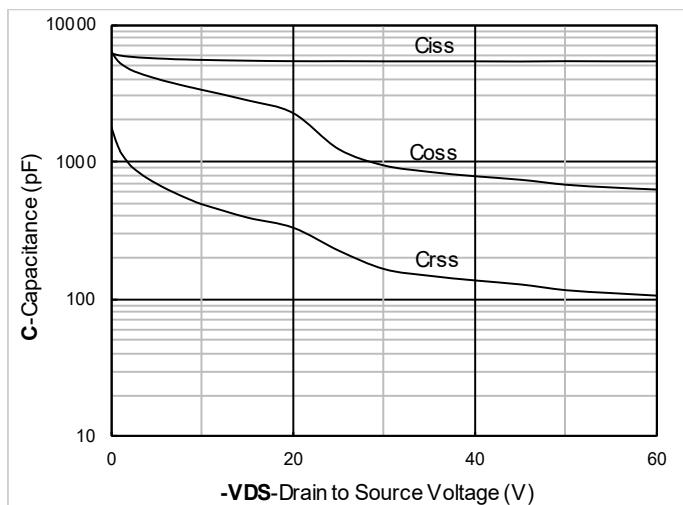


Figure 3. Capacitance Characteristics

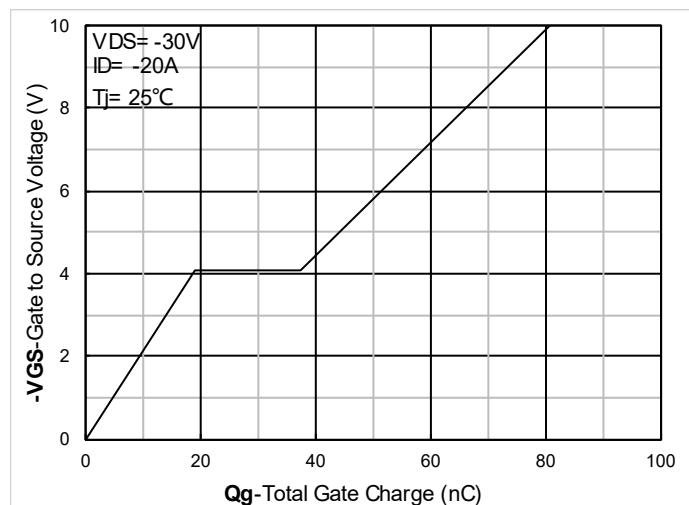


Figure 4. Gate Charge

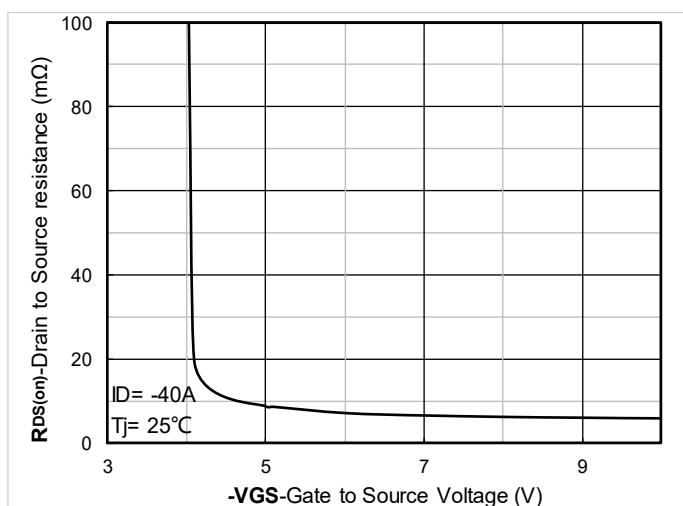


Figure 5. On-Resistance vs Gate to Source Voltage

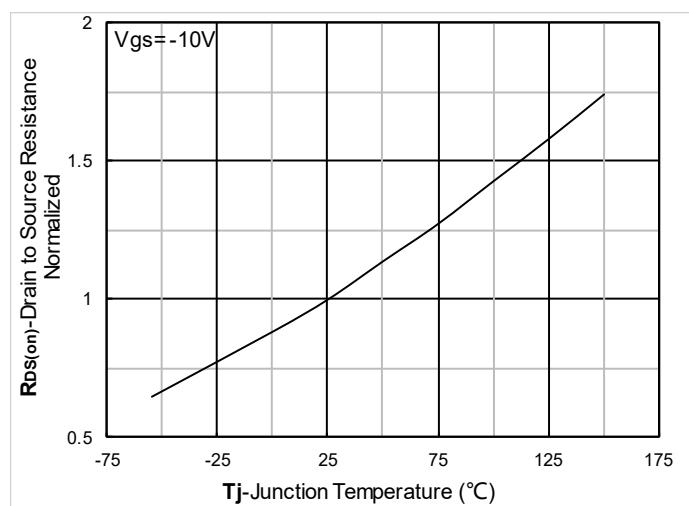


Figure 6. Normalized On-Resistance

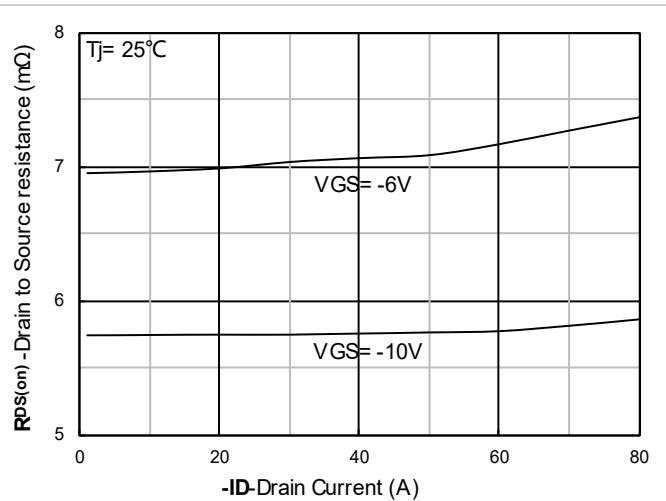


Figure 7. RDS(on) VS Drain Current

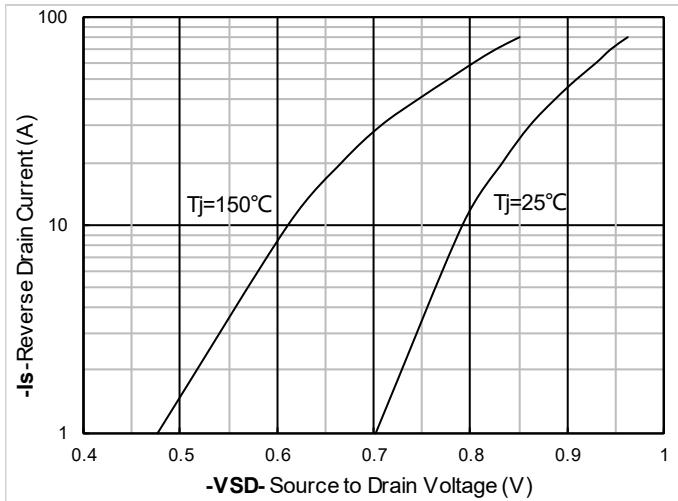


Figure 8. Forward characteristics of reverse diode

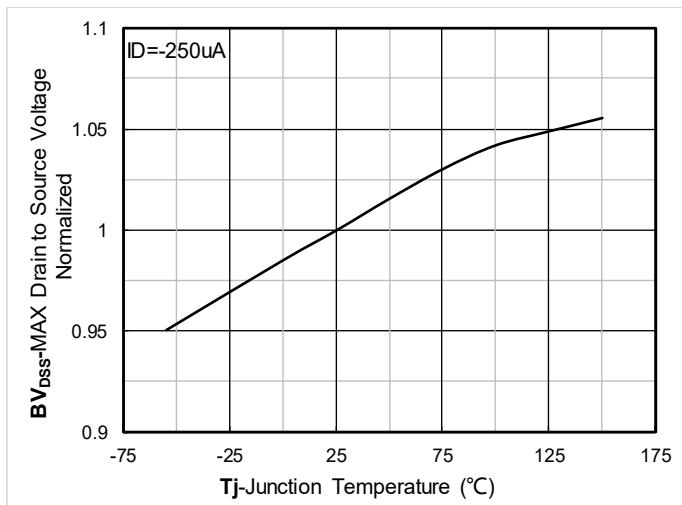


Figure 9. Normalized breakdown voltage

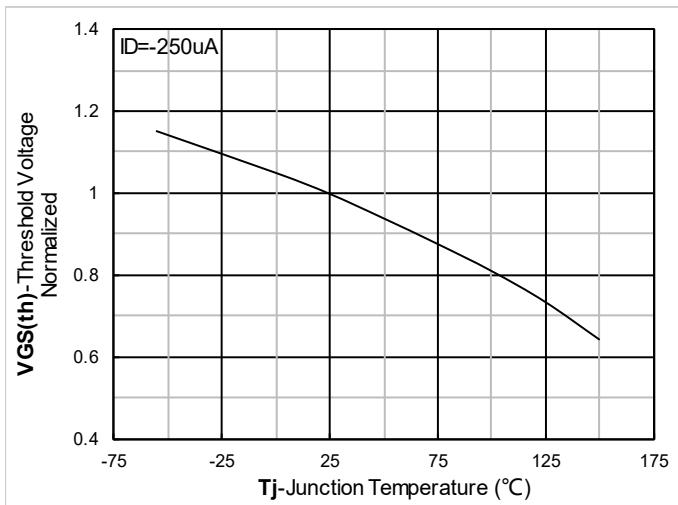


Figure 10. Normalized Threshold voltage

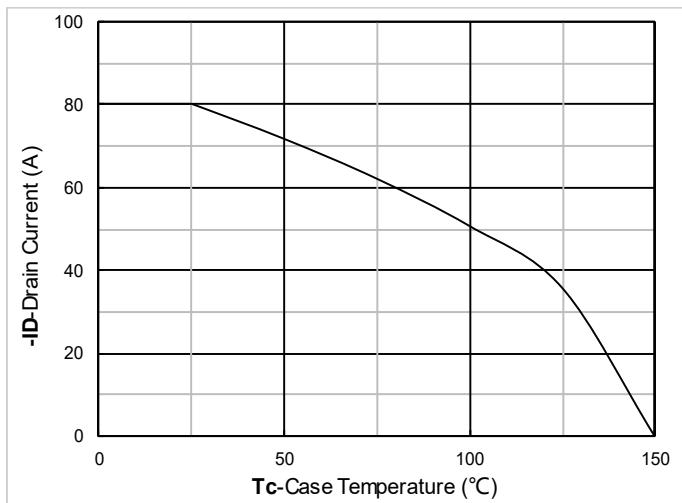


Figure 11. Current dissipation

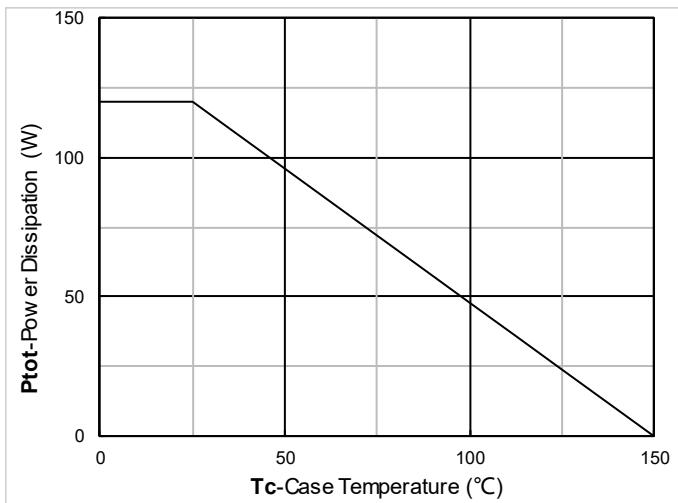


Figure 12. Power dissipation



# YJG80GP06BQ

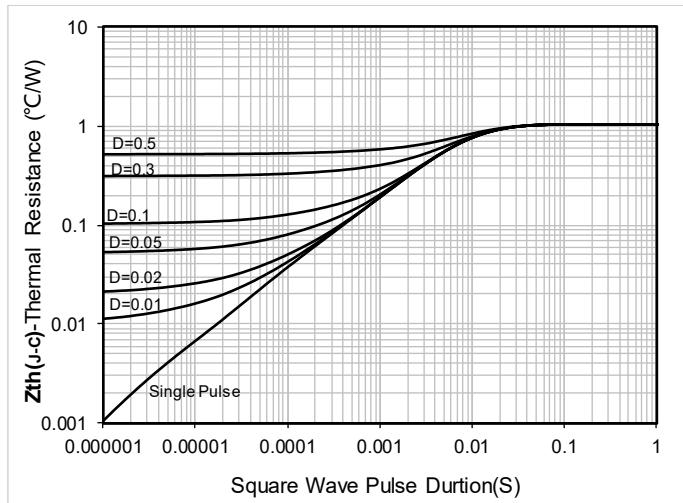


Figure 13. Maximum Transient Thermal Impedance

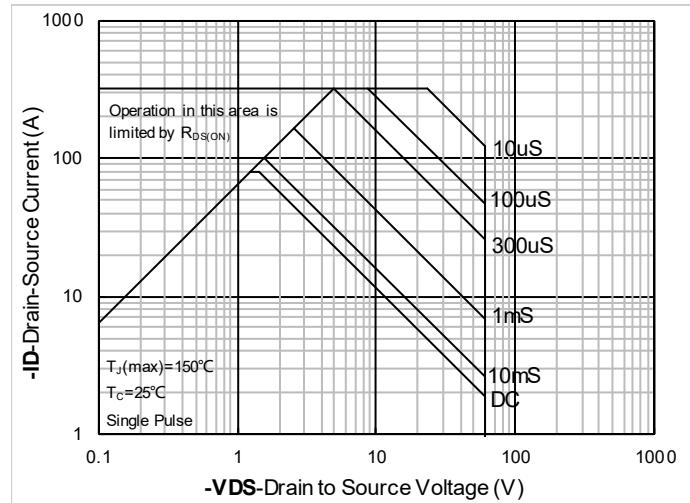
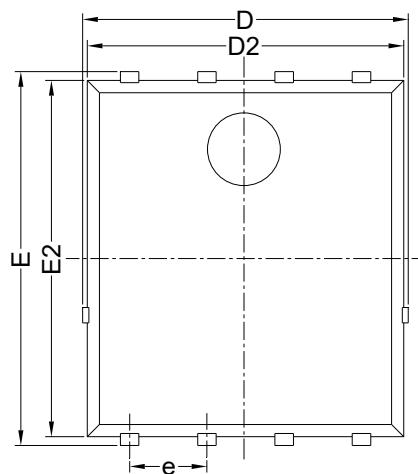
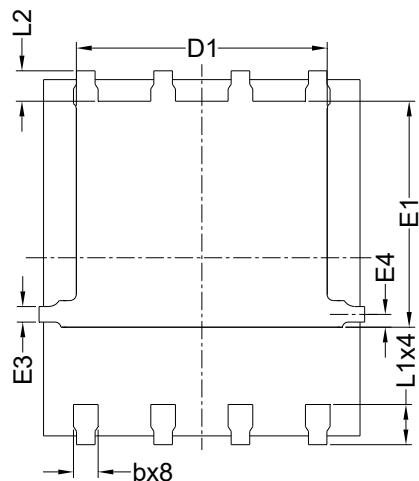
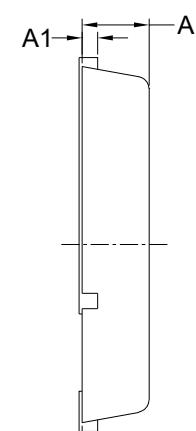
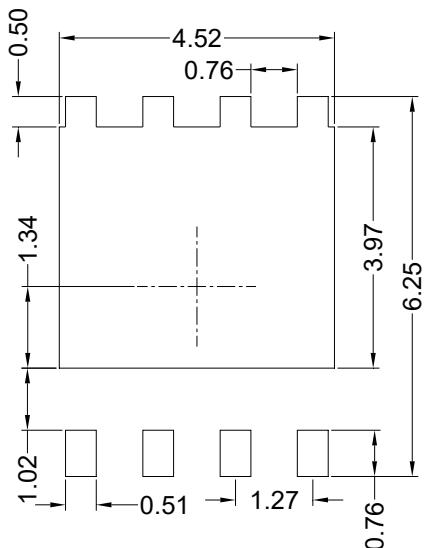


Figure 14. Safe Operation Area



## ■ PDFN5060-8L-B-1.1MM Package information

Top View  
正面视图Bottom View  
背面视图Side View  
侧面视图Suggested Solder Pad Layout  
Top View

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	5.15	5.35	5.55
E	5.95	6.15	6.35
A	1.00	1.10	1.20
A1	0.254 BSC		
A2			0.10
D1	3.92	4.12	4.32
E1	3.52	3.72	3.92
D2	5.00	5.20	5.40
E2	5.66	5.86	6.06
E3	0.254 REF		
E4	0.21 REF		
L1	0.56	0.66	0.76
L2	0.50 BSC		
b	0.31	0.41	0.51
e	1.27 BSC		

## Note:

1. Controlling dimension:in millimeters.
2. General tolerance: $\pm 0.10\text{mm}$ .
3. The pad layout is for reference purposes only.



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